Themid-infrared AC $H$ alle ect in optim ally-doped $\mathrm{Bi}_{2} \mathrm{Sr}_{2} \mathrm{C}$ aC $\mathrm{u}_{2} \mathrm{O}_{8+}$

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#### Abstract

A novel heterodyne polarom etry system determ ines the frequency dependence from 900 to 1100 am 1 and tem perature dependence from 35 to 330 K of the H alltransport in single crystal, optim ally doped $\mathrm{Bi}_{2} \mathrm{Sr}_{2} \mathrm{CaCu}_{2} \mathrm{O}_{8+}$. The results show a signi cant disconnect from the behavior of the H all angle in the existing data for YBCO in the far-infrared, which indicate a negative value for the real part of the $H$ all angle above $250 \mathrm{~cm}^{1}$, whereas that of the current work at $1000 \mathrm{~cm}^{1}$ is positive. The current work when analyzed using an extended D rude form alism results in a $H$ all $m$ ass com parable to the ARPES Ferm im ass and a scattering rate com parable to the low frequency conductivity and $H$ alle ect scattering rates, which, how ever, are only $1 / 4$ of the $m$ inim um ARPES values.


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W hile the D C and infrared conductivities reveal the overall response of a system to an electric eld, the H all e ect reveals the sign of the carriers as w ell as som e inform ation as to the path taken by them. It essentially probes the ability of the carriens to veer or bend their course. Q uantities frequently used to represent the e ect are the $H$ all angle ${ }_{H}$ or the longitudinal and transverse conductivities $x x$ and $x y$ w ith

$$
\begin{equation*}
\tan _{H}=\frac{x y}{x x} \tag{1}
\end{equation*}
$$

These quantites becom e com plex response functions for AC elds. The collection of existing $m$ easurem ents of the DC and AC Halle ect in high tem perature superconductors has revealed a m ost curious behavior, whose description de es all current m odels, while, how ever, apparently falling short of suggesting a com prehensive theortical approach on its own. Some of the di culty of identifying pattems which can be simply expressed by $m$ eans of som e phenm enology arises from the fact that one is hesitant to $m$ ake direct com parisons betw een the the existing AC Hall m easurem ents conducted on epitaxial $\mathrm{m} s$ of YBCO $w$ th thoses of results of ARPES and STM on single crystalBSCCO.TheYBCO m sare tw inned on a micron scale and the conductivity is further com plicated by the existance of $\mathrm{CuO}_{2}$ chains. The m id-infrared H allm easum ents reported here are the rst on BSCCO single crystal and should cover som e of the distance in rem edying this predicam ent.

To appreciate the present state of the search for pattems and phenom enology consider the rst of the earlier work [19, follow ed squared tem perature behavior:

$$
\begin{equation*}
\cot _{\mathrm{H}}=\mathrm{A}+\mathrm{BT}^{2} \tag{2}
\end{equation*}
$$

w ith A proportional to Zn doping. The $\mathrm{T}^{\mathrm{n}}$ behavior, for $n=2$, supported two $m$ odels such as those asso-
ciated with spin-charge separation in the cuprates $\left[\overline{4 n}_{1}^{\prime}\right]$. H ow ever, later system atic studies of both single layer
 vealed that $\mathrm{n}=1.78$ for optim al doping and n clearly depends on oxygen doping, approaching $n=2$ only in the underdoped regim e. The far-infrared extension of the Halle ect explored in YBCO ${ }^{[ }\left[\begin{array}{l}{[ } \\ \hline\end{array}\right.$ ent phenom enology involving a squared Lorentzian w ith
 A theoretical justi cation for this response has been obtained by Varm a and Abraham $s$ in term $s$ of $m$ arginal Ferm iliquid $m$ odel in the form [9]:

$$
\begin{equation*}
\tan _{H}=\frac{!_{H}}{H}+\frac{!_{H}}{2_{H}^{2}} \tag{3}
\end{equation*}
$$

where is related to Ferm i surface averages of derivatives of the elastic scatteering and $H$ is the inelastic relaxation rate proportional to tem perature and which is replaced w ith $H \quad i!$ for ac. In the dc lim it this form accom $m$ odates the revised exponent of 1.78 and the Zn doping. This far-infrared behavior contrasts sharply with that suggested by the m id-infrared data for Y BCO [1d] obtained using the spectral lines of a $\mathrm{CO}_{2}$ laser. W hen the cotangent of the H allangle is tted to a D rudem odel the resulting H all m ass and the H all scattering rate, to w ithin the accuracy of the data, display no frequency dependence w thin the range from 949 to $1079 \mathrm{~cm}^{1}$. H ow ever, the $H$ all frequency displays a slight decrease w ith increasing tem perature, w hereas the $H$ all scattering rate increases linearly w th tem perature from near zero at $T_{c}$ to over 300 cm 1 at 250 K . H ow ever, the chain contributions to the conductivity for these tw inned sam ples, grown by pulsed laser deposition, introduces considerable uncertainty in these results for the scattering rates and H all m ass.

In developing an understanding of transport in the cuprates the relation between the transport proper-
ties and the Angle Resolved Photoem ission Spectra (ARPES) w ill be im portant. In the past several years ARPES has m apped the Ferm i surface and identi ed the d-w ave symm etry of the order param eter. U sing $\mathrm{k}_{\mathrm{F}}=0: 446 \mathrm{~A}^{1}$ and $\mathrm{V}_{\mathrm{F}}=1: 8 \mathrm{eVA}$ [11, $\left.1 \overline{1}_{1}^{1}\right]$ the ARPES Ferm i surface $m$ ass is

$$
\begin{equation*}
m_{\mathrm{F}}=\frac{h k_{\mathrm{H}}}{\mathrm{v}_{\mathrm{F}}}=h k_{\mathrm{H}} \quad \frac{1}{\mathrm{~h}} \frac{@ \mathrm{E}}{\mathrm{@k}} \tag{4}
\end{equation*}
$$

$w$ here $k_{F}=0: 69 \mathrm{~A}$ is the Ferm iw avenum ber for the holelike surface. T he quasiparticle relaxation rate is related to the width of the ARPES spectral density function at the Ferm i energy. $W$ thin $m$ any body perturbation theory the low frequency current relaxtion rate is given directly by the EDC line widths or from the MDC line $w$ idths, $k$, as $F \quad V_{F} k$, where $V_{F}$ is the $m$ easured Ferm i velocity. The existing ARPES data on BSCCO nds that / T. However, them inim um values for deduced from ARPES corresponding to the ( ; ) or nodal direction on the Ferm i surface are four tim es larger than the $m$ easured $\mathbb{R}$ relaxation rates. It is not yet known whether this discrepancy can be reconciled in term $s$ of sm all angle scattering issues or Ferm i liquid e ects or if it requires a $m$ ore exotic interpretation.

A dditionally A RPES m easurem ents have revealed that there is a kink in the quasiparticle dispersion curve, which for $\mathrm{Bi}_{2} \mathrm{Sr}_{2} \mathrm{CaCl}_{2} \mathrm{O}_{8+}$ occurs at about $\left.50 \quad 15 \mathrm{meV} \quad[1]_{1}^{-1}\right]$. The change in slope results in a reduction in velocity of around a factor of two above the kink. Z.X. Shen et al. [14] also report this kink occurring in LSCO at around 70 meV . The interprertation of this feature is controversial and includes electron-phonon interaction, the opening of a 50 meV superconducting gap, a spin excitation, or som e type of interaction $w$ th the theorized stripe phase.

The experim entalsystem of the current work $m$ easures the very sm all com plex Faraday angle im parted to $\mathrm{CO}_{2}$ laser radiation traveling penpendicular to and transm itted by the sam ple im $m$ ersed in a penpendicular $m$ agnetic
eld. The system is the same as that used by in the earlier Y BCO study [1]] w th the addition of an in line calibration system and a continuous stress-firee tem perature scan provision, and further $m$ odi ed to place a difraction-lim ited spot on the sam ple w ith post-sam ple spatial ltering [1]

T he sam ple of the current w ork w as cleaved or rather, peeled from a single bulk crystal of $\mathrm{B} \dot{1}_{2} \mathrm{Sr}_{2} \mathrm{CaCu}_{2} \mathrm{O}_{8+}$ grown by the oating zone $m$ ethod and then placed in therm al contact w ith a wedged $\mathrm{BaF}_{2}$ crystal. M easure$m$ ent of the AC $m$ agnetic susceptance of this $m$ ounted peeled segm ent revealed a $\mathrm{T}_{\mathrm{c}}$ of 92 K w ith a width of less than 1 K . This $m$ easurem ent, perform ed after all of the $H$ allm easurem ents had been com pleted, establish the integrity of the sample and recom $m$ end the $H$ all data as representative of optim ally doped BSCCO. Infrared conductivity data from $m$ easurem ents perform ed on bulk


FIG .1: The realand im aginary parts of ${ }_{\text {H }_{1}^{1}}$ for 2212 B SC C O versus tem perature. The inset displays ${ }_{H}{ }^{\frac{H}{1}}$ at 300 K and versus w avenum ber .
crystals from the sam e batch supplied the realand im aginary parts of xx required to obtain the H all angle from the Faraday angle data. The calculation of xy considered the multilayer re ection e ects within the BSCCO Im [1\$].
To form $H$ one divides $x y$ by $x x$ corresponding to the sam e tem perature and frequency. Since we wish to exam ine that part of the $H$ all angle related to the free carriers it is necessary to rem ove the contributions to xx com ing from interband transitions which occur above 1 volt. These transitions contribute essentially nothing to $x y$ at the frequencies of these experim ents. Therefore, before taking the ratio, we rem oved their contribution to the im aginary part of xx using the value in nity $=4: 6$ from $Q$ uijada [1] $\left.{ }^{-1}\right]$. This increases $\operatorname{Re}\left({ }_{\text {н }}\right)$ by about 5\% and reduces $\operatorname{Im}\left({ }_{H}\right)$ by about $5 \%$.

Figure ${ }_{1}^{11}$ displays the resulting values of ${ }_{H}{ }^{1}$. The m ost striking feature of the m id-infrared H all angle response is its strong tem perature dependence in com parison $w$ th the tem perature dependence of $x x$ at these frequencies [1] [1]. The observed response is not consistent w th the Lorentzian squared form found in YBCO at far-infrated frequencies which, in particular, im plies a positive $\operatorname{Re}\left({ }_{H}\right)$ at these frequencies. Indeed the response in the $m$ id-infrared is found to be close to that of a D rudem odel ${ }_{H}=!_{H}=\left(\quad\right.$ i! ). TheRe( $\left.{ }_{H}{ }^{1}\right)$ in $F$ ig. $\underline{1}_{1}^{\prime}$ is nearly frequency independent but strongly tem perature dependent. The $\operatorname{Im}\left({ }_{H}{ }^{1}\right)$ is only weakly tem perature dependent and has a power law frequency dependence at 300 K but is of som ew hat lower degree than the linear dependence ! expected for a D rude $m$ odel. This suggests that by $1000 \mathrm{~cm}^{1}$ the system is approaching but has not yet reached the high frequency asym ptotic $D$ rude form. The condition for achieving this asym ptotic form are that the frequency $m$ ust be higher than all the charac-


FIG. 2: Im ( $x x$ ) $=\operatorname{Re}(x x)$ vs. frequency for single crystal 2212 B SCCO at di erent tem peratures.
teristic frequencies of the system, including the quasiparticle relaxation rate. W hile 100 meV is higher than the superconducting gap, the phonon energies and the neutron m agnetic resonance it is still below the estim ated antiferrom agnetic coupling energy $\mathrm{J} \quad 200 \mathrm{~m} \mathrm{eV}$ for the cuprates. Indeed the longitudinal conductivity has not achieved the w idely reported asym ptotic behavior as can be seen in Fig. ${ }_{1}$, 1 , where by $1000 \mathrm{~cm}^{1} \mathrm{Im}()=\operatorname{Re}()$ has becom e nearly frequency independent in contrast to the linear frequency dependence for a D rude response.
$F$ igure ${ }^{1} \overline{3}$ com pares the realpart of the $H$ all angle w ith that from the far-infrared data $\left.\overline{7}_{1}\right]$. W e observe a disconnect betw een the behavior of the far-and $m$ id-infrared H all angle. Starting at about $230 \mathrm{~cm}^{1}$ the real part of the H all angle for low tem peratures appears to be negative. H ow ever, as noted above it is positive at all tem peratures above $T_{c}$ in the $m$ id-infrared. $T$ he thin lines are ts of the full com plex far-infrared H all angle data to squared Lorentzians. H ow ever, the extension of the real part into the $m$ id-infrared rem ains negative unlike the data which are positive. T here are num erous ways to accom $m$ odate this plunge in the real part of the H all angle at $300 \mathrm{~cm}^{1}$ and to join these results w th those of the $m$ id-infrared of the current work. All would require at least one $m$ inim um and at least one $m$ axim um betw een 300 and $1000 \mathrm{~cm}^{1}$ suggesting a resonance in this frequency interval. N o such feature is seen in the data for xx [2]_]. H ow ever, a peak is present at $300 \mathrm{~cm}^{1}$ in the phase of $x x$ in the plot of $\operatorname{Im}(x x)=\operatorname{Re}(x x)$ at 100 K shown in F ig. $\overline{\mathrm{L}}$. It is interesting to note that this feature in the phase is not predicted by most models that have been proposed for the conductivity in the cuprates, for exam ple, the coldspot $m$ odel [1] []. Further, its frequency roughly corresponds to num erous other phenom ena including the 41 meV spin resonance, the $50 \quad 15$ meV phonon interaction [ $[1]$, and the quasiparticle band w idth of the three band $\mathrm{H} u \mathrm{ub}$ bard m odel.


FIG. 3: The real and im aginary parts of ${ }_{H}=T$ esla versus tem perature for 2212 B SC C O. Them id-in frared data is show $n$ in the inset with expanded axes. The brown points in the inset correspond to 300 K . T he other colors of the points at $950 \mathrm{~cm}^{1}$ w ithin the inset corresond to the sam e tem peratures as in the $m$ ain plot.

In view of the near $D$ rude behavior of the $m$ id $-\mathbb{R} H$ all data we have used the D rude model to extract the param eters of the $m$ odel $!_{H}$ and ${ }_{H}$ and to exam ine their frequency and tem perature dependence. W e express ! ${ }_{\mathrm{H}}$ in term s of the $H$ allm ass de ned as $m_{H}=e B=!_{\text {н }} C$. The data are show $n$ in $F$ igs. to be in rem arkably good agreem ent, especially at $\mathrm{T}_{\mathrm{C}}$, w th the hole e ective m ass at the Ferm i level deduced from ARPES m easurem ents. The inset data in Fig. $\bar{A} 1$ dicates a decreasing $m$ ass $w$ ith frequency in accord $w$ ith the general expectation that it approach the band value estim ated at about half the value at $\mathrm{E}_{\mathrm{F}}$. T he data also indicate an increasing $m$ ass $w$ ith tem perature, which is quite counter to the expectations for strongly interacting system s. H ow ever, we note that $н$ and the carrier relaxation rate in general is an increasing function of $T$ achieving its sm allest value at $\mathrm{T}_{\mathrm{c}}$. A s the H all angle (or inverse H all angle) can be expanded asym ptotically as a series in $z={ }_{n}=$ ! (w here $n$ are various averages of the scattering rates) the asym ptotic behavior is m ost closely achieved at the low est tem peratures where $z$ is sm all. Indeed it is seen that $\mathrm{m}_{\mathrm{H}}$ is in excellent agreem ent w ith ARPES at low T and deviates as T is increased.

F igure ${ }^{\prime \prime} \bar{h}^{\prime}$ ' displays a $H$ all $m$ ass, which is roughly tw ice the value of the longitudinal $m$ ass calculated from $x x$ in the m id-infrared. The frequency dependences for the H all m ass and longitudinal m ass are sim ilar displaying a slow decrease w ith increasing frequency. H ow ever, the tem perature dependences of the $m$ asses are opposite each other w th the H allm ass actually increasing about 20\% over the tem perature range of 100 to 300 K . Finally, the sam eARPES m easurem entswhich im ply a very di erent scattering rate nd a fulldressed $m$ ass at the Ferm i level which is nearly equal to the $m$ easured $m$ id-infrared $H$ all m ass.


FIG. 4: The m id-infrared $H$ all $m$ ass (thin line) and the ARPES Ferm i surface $m$ ass (thick line) both versus tem perature. The m id-infrared H all m ass is also show n in the inset versus frequency.

The linear tem perature dependence of the $H$ all scattering rate in the $m$ id-infrared also disagrees $w$ ith the ARPES results for Im [12ㄹ], which im ply a decreasing tem perature dependence $w$ ith increasing frequency as is also seen in $x x$. A lso $m$ arginal Ferm i liquid theory, which posits a linear tem perature dependence of the scattering is at odds w th the lack of frequency dependence. A ny signi cant frequency dependence would cause a signi cant positive intercept in the zero tem perature projection of the norm al state scattering rate in $F$ ig. ${ }^{\overline{5}} \mathbf{1} 1$. T he lack of frequency dependence of the scattering rate of the current work on the other hand contravenes both Ferm i liquid and $m$ arginal Ferm i liquid theories, which claim a strong frequency dependence for the scattering rate at tem peratures low com pared to the photon energies of the experim ent. We nd little or no frequency dependence of the scattering rate at ! = $1000 \quad 125 \mathrm{~m} \mathrm{eV}$. T he farinfrared scattering rate when com pared to that of the $m$ id-infrared exhibits the sam e linear increase $w$ ith tem perature. H ow ever, the projection of the norm al state m id-infrared scattering rate to zero tem perature is negative. This feature was also observed for Y BCO [10

Figure's also show s the relaxation rates deduced from $m$ easured quantities from the $m$ id $-\mathbb{R} \mathrm{H}$ all data and a num ber of other experim ents. These include $\mathbb{R}$ conductivity for BSCCO [ [ $]_{1}$ ] determ ined from the slope in Fig.

$$
\begin{equation*}
=\frac{}{1+(!)}=!\frac{\operatorname{Re}(1=)}{\operatorname{Im}(1=)}=!\frac{\operatorname{Re}()}{\operatorname{Im}()} \tag{5}
\end{equation*}
$$

A lso included are: the relaxation rate deduced from xx for YBCO extrapolated to zero frequency designated \Q uijada " [1] $]$; the H all relaxation rates designated \G rayson ${\underset{H}{2}}_{2}$ "and $\backslash \mathrm{G}$ rayson xy " both for YBCO in the far-infrared, the rst using using the squared Lorentzian analysis and the second using a sim ple D rude applied to


FIG. 5: The scattering rates from di erent $m$ easurem ents com pared. T he thick black line dem onstrates the tem perature dependence of the H all scattering rate in the m id-in frared region. T he $m$ id-in frared $H$ all scattering rate is also show $n$ in the inset versus frequency.
xy $\left[\begin{array}{l}{[7]}\end{array}\right]$ the terahertz relaxation rate designated $\backslash C$ orson
" [19] deduced from for BSCCO at $02-1.0 \mathrm{THz}$; the H all relaxation rate for Y B CO designated $\backslash \mathrm{R}$ igal H " deduced from $\quad$ H ${ }^{2} 0_{1}^{\prime} 1$; and the A R P ES zero frequency value for for BSCCO designated $\backslash V a l l a \quad$ " $[1+1+]$. Except for the ARPES result, the di erent relaxation rates are in rem arkable agreem ent w ith each other, especially at low T. H ow ever, they are all signi cantly sm aller than the hole scattering rates at $E_{F}$ deduced from ARPES in the ( ; ) direction where the linew idths take on their minimum values.

These results suggest a universal linear $T$ relaxation rate in the hole doped cuprates. M ore rem arkably they also suggest that the transport relaxation rate is tem perature dependent but not frequency dependent. In this case the apparent frequency dependence of the infrared relaxation rate deduced from $m$ ay not represent an inelastic scattering e ect but drives instead from som e other mechanism such as that suggested by Io e and $M$ illis. Therefore these results suggest that current relaxation in the optim ally doped cuprates is quasi-elastic.

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